TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC74VHC273F,TC74VHC273FW,TC74VHC273FT,TC74VHC273FK

Octal D-Type Flip-Flop with Clear

The TC74VHC273 is an advanced high speed CMOS OCTAL D-TYPE FLIP FLOP fabricated with silicon gate C²MOS technology.

It achieves the high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation.

Information signals applied to \boldsymbol{D} inputs are transferred to the \boldsymbol{Q} outputs on the positive going edge of the clock pulse.

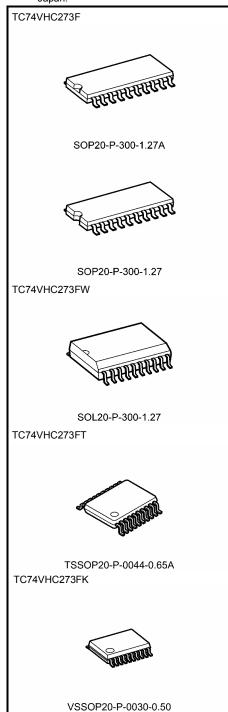
When the $\overline{\text{CLR}}$ input is held "L", the Q outputs are at a low logic level independent of the other inputs.

An input protection circuit ensures that 0 to 5.5 V can be applied to the input pins without regard to the supply voltage. This device can be used to interface 5 V to 3 V systems and two supply systems such as battery back up. This circuit prevents device destruction due to mismatched supply and input voltages.

Features

- High speed: $f_{max} = 165 \text{ MHz}$ (typ.) at $V_{CC} = 5 \text{ V}$
- Low power dissipation: $I_{CC} = 4 \mu A \text{ (max)}$ at $T_{a} = 25 \text{°C}$
- High noise immunity: V_{NIH} = V_{NIL} = 28% V_{CC} (min)
- Power down protection is provided on all inputs.
- $\bullet \quad Balanced\ propagation\ delays\hbox{:}\ t_{pLH} \simeq t_{pHL}$
- Wide operating voltage range: VCC (opr) = 2 to 5.5 V
- Low noise: VOLP = 0.9 V (max)
- Pin and function compatible with 74ALS273

Note: xxxFW (JEDEC SOP) is not available in Japan.



Weight

 SOP20-P-300-1.27A
 : 0.22 g (typ.)

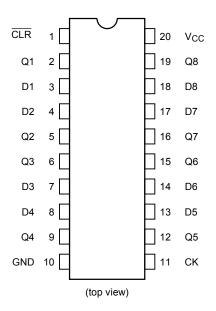
 SOP20-P-300-1.27
 : 0.22 g (typ.)

 SOL20-P-300-1.27
 : 0.46 g (typ.)

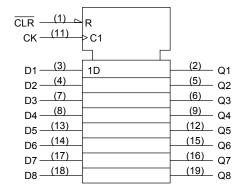
 TSSOP20-P-0044-0.65A
 : 0.08 g (typ.)

 VSSOP20-P-0030-0.50
 : 0.03 g (typ.)

Pin Assignment



IEC Logic Symbol

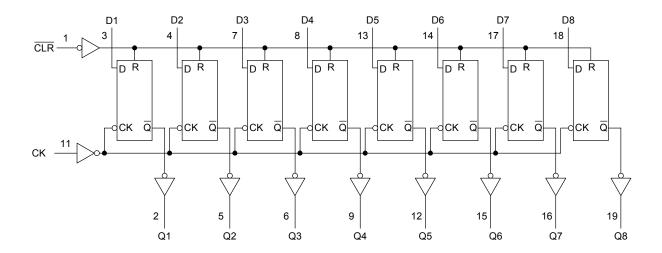


Truth Table

	Inputs		Output	Function		
CLR	D CK		Q	FullClion		
L	Х	Х	L	Clear		
Н	L	Ļ _]	L			
Н	Н		Н	_		
Н	Х	\neg	Qn	No Change		

X: Don't care

System Diagram





Absolute Maximum Ratings (Note)

Characteristics	Symbol	Rating	Unit
Supply voltage range	V _{CC}	–0.5 to 7.0	V
DC input voltage	V _{IN}	−0.5 to 7.0	V
DC output voltage	V _{OUT}	-0.5 to V _{CC} + 0.5	V
Input diode current	I _{IK}	-20	mA
Output diode current	lok	±20	mA
DC output current	lout	±25	mA
DC V _{CC} /ground current	Icc	±75	mA
Power dissipation	PD	180	mW
Storage temperature	T _{stg}	-65 to 150	°C

Note: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Recommended Operating Conditions (Note)

Characteristics	Symbol	Rating	Unit
Supply voltage	V _{CC}	2.0 to 5.5	V
Input voltage	V _{IN}	0 to 5.5	V
Output voltage	V _{OUT}	0 to V _{CC}	V
Operating temperature	T _{opr}	−40 to 85	°C
Input rise and fall time	dt/dv	0 to 100 (V _{CC} = 3.3 ± 0.3 V)	nc/\/
input rise and rail time	ui/uv	0 to 20 (V _{CC} = 5 \pm 0.5 V)	ns/V

Note: The recommended operating conditions are required to ensure the normal operation of the device.

Unused inputs must be tied to either VCC or GND.



Electrical Characteristics

DC Characteristics

Characteristics	Symbol	Test Condition			٦	Ta = 25°C		Ta = -40 to 85°C		Unit
	.,			V _{CC} (V)	Min	Тур.	Max	Min	Max	
High lovel input		_		2.0	1.50		_	1.50		V
High-level input voltage	V _{IH}			3.0 to 5.5	V _{CC} × 0.7	_	_	V _{CC} × 0.7	_	
Low-level input				2.0	_		0.50	_	0.50	
voltage	V_{IL}		_	3.0 to 5.5	_	_	V _{CC} × 0.3	_	V _{CC} × 0.3	V
	Voн			2.0	1.9	2.0	_	1.9	_	V
		V _{IN} = V _{IH} or V _{IL}	$I_{OH} = -50 \mu A$	3.0	2.9	3.0	_	2.9	_	
High-level output voltage				4.5	4.4	4.5	_	4.4		
			$I_{OH} = -4 \text{ mA}$	3.0	2.58	-	_	2.48		
			$I_{OH} = -8 \text{ mA}$	4.5	3.94		_	3.80	_	
	V _{OL}			2.0		0.0	0.1		0.1	
		$V_{IN} = V_{IH}$ or V_{IL}	$I_{OL} = 50 \ \mu A$	3.0	_	0.0	0.1	_	0.1	
Low-level output voltage				4.5	_	0.0	0.1	_	0.1	V
Ü			$I_{OL} = 4 \text{ mA}$	3.0	_	_	0.36	_	0.44	
			$I_{OL} = 8 \text{ mA}$	4.5	_	_	0.36	_	0.44	
Input leakage current	I _{IN}	V _{IN} = 5.5 V or GND		0 to 5.5	_		±0.1		±1.0	μА
Quiescent supply current	I _{CC}	V _{IN} = V _{CC} or	V _{IN} = V _{CC} or GND		_		4.0		40.0	μА

Timing Requirements (input: $t_r = t_f = 3 \text{ ns}$)

Characteristics	Symbol	Test Condition	st Condition		Ta = 25°C		Unit
			V _{CC} (V)	Тур.	Limit	Limit	
Minimum pulse width (CK)	t _{w (L)}		3.3 ± 0.3	_	5.5	6.5	ns
Minimum pulse width (CK)	t _{w (H)}	_	5.0 ± 0.5	_	5.0	5.0	
Minimum pulse width (CLR)	t _{w (L)}	_	3.3 ± 0.3	_	5.0	6.0	ns
Millimum puise width (CER)			5.0 ± 0.5	_	5.0	5.0	115
Minimum set-up time	t _s	_	3.3 ± 0.3	_	5.5	6.5	ns
Millimum set-up time			5.0 ± 0.5	_	4.5	4.5	115
Minimum hold time	t _h	_	3.3 ± 0.3	_	1.0	1.0	20
Minimum noid time			5.0 ± 0.5	_	1.0	1.0	ns
Minimum removal time (CLR)	4		3.3 ± 0.3		2.5	2.5	no
Willimum Temoval time (CLR)	t _{rem}	_	5.0 ± 0.5	_	2.0	2.0	ns



AC Characteristics (input: $t_r = t_f = 3$ ns)

Characteristics	Symbol		Test Condition		Ta = 25°C			Ta = −40 to 85°C		Unit
	,		V _{CC} (V)	C _L (pF)	Min	Тур.	Max	Min	Max	
			3.3 ± 0.3	15	_	8.7	13.6	1.0	16.0	ns ns
Propagation delay time	t_{pLH}		3.5 ± 0.5	50	_	11.2	17.1	1.0	19.5	
(CK-Q)	t_{pHL}	_	5.0 ± 0.5	15	_	5.8	9.0	1.0	10.5	
			5.0 ± 0.5	50	_	7.3	11.0	1.0	12.5	
		_	3.3 ± 0.3	15	_	8.9	13.6	1.0	16.0	
Propagation delay time	t _{pHL}		3.3 ± 0.3	50	_	11.4	17.1	1.0	19.5	- ns
(CLR -Q)			5.0 ± 0.5	15		5.2	8.5	1.0	10.0	
				50	_	6.7	10.5	1.0	12.0	
	f _{max}	_	3.3 ± 0.3	15	75	120		65	_	- MHz -
Maximum clock				50	50	75		45	_	
frequency			5.0 ± 0.5	15	120	165		100	_	
				50	80	110	_	70	_	
Output to output skew	t _{osLH}	(Note 1)	3.3 ± 0.3	50		_	1.5		1.5	ns
Output to output skew	t _{osHL}	(Note 1)	5.0 ± 0.5	50	_	_	1.0	_	1.0	115
Input capacitance	C _{IN}					4	10	_	10	pF
Power dissipation capacitance	C _{PD}			(Note 2)		31				pF

Note 1: Parameter guaranteed by design.

$$t_{OSLH} = |t_{pLHm} - t_{pLHn}|, t_{OSHL} = |t_{pHLm} - t_{pHLn}|$$

Note 2: CPD is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

$$I_{CC (opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/8 \text{ (per bit)}$$

And the total C_{PD} when n pcs.of flip flop operate can be gained by the following equation:

$$C_{PD} \ (total) = 22 + 9 \cdot n$$

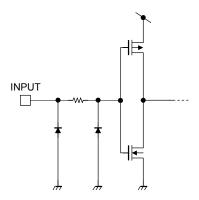
Noise Characteristics (input: $t_r = t_f = 3$ ns) (Note)

Characteristics	Symbol	Test Condition		Ta = 25°C		Unit
Characteristics	Symbol		V _{CC} (V)	Тур.	Max	OTIIC
Quiet output maximum dynamic V _{OI}	V _{OLP}	C _I = 50 pF	5.0	0.5	0.8	V
Quiet output maximum dynamic VOL		OL = 50 μr		(0.6)	(0.9)	
Quiet output minimum dynamic V _{OI}	V _{OLV}	C _I = 50 pF	5.0	-0.5	-0.8	V
Quiet output minimum dynamic vol		Ο[– 30 μι		(-0.6)	(-0.9)	
Minimum high level dynamic input voltage	V_{IHD}	C _L = 50 pF	5.0	_	3.5	V
Maximum low level dynamic input voltage	V_{ILD}	C _L = 50 pF	5.0	_	1.5	V

Note: The value in () only applies to JEDEC SOP (FW) devices.

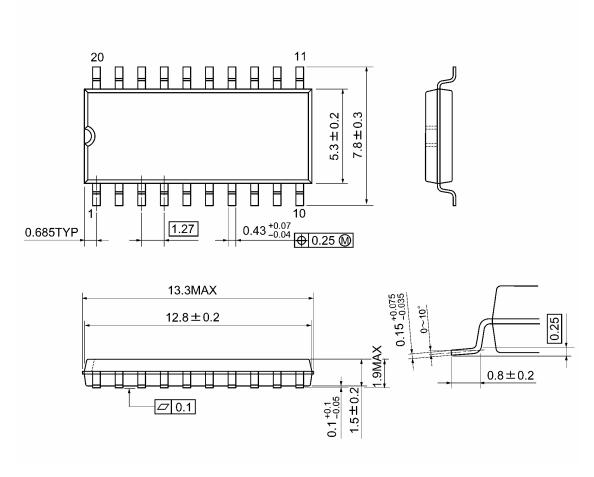


Input Equivalent Circuit



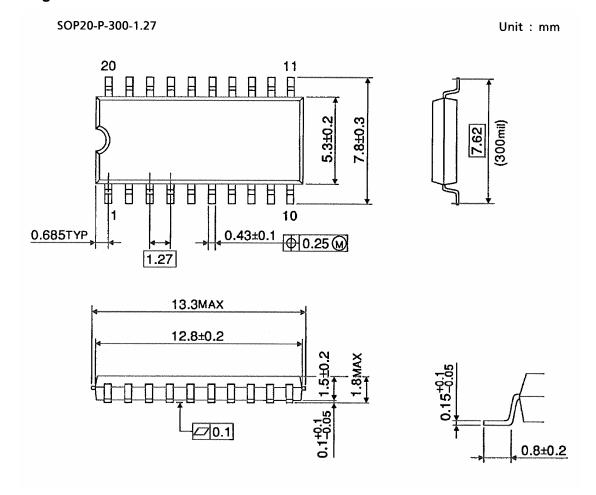


SOP20-P-300-1.27A Unit: mm



Weight: 0.22 g (typ.)

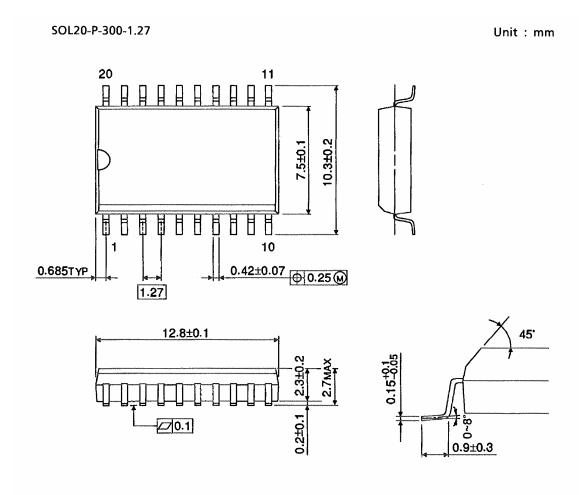




Weight: 0.22 g (typ.)



Package Dimensions (Note)



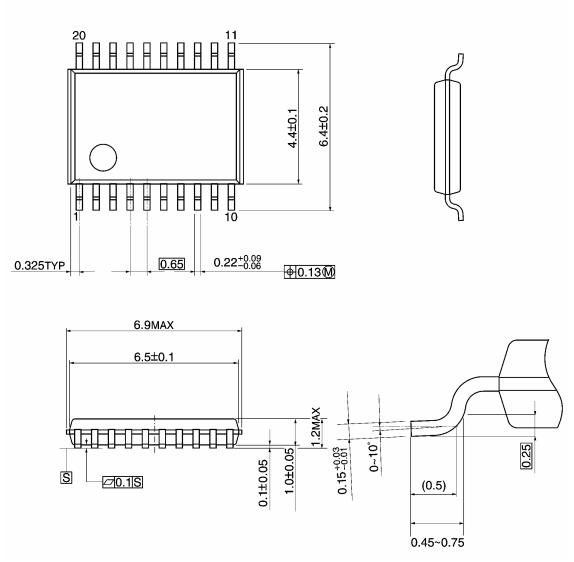
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Note: This package is not available in Japan.

Weight: 0.46 g (typ.)

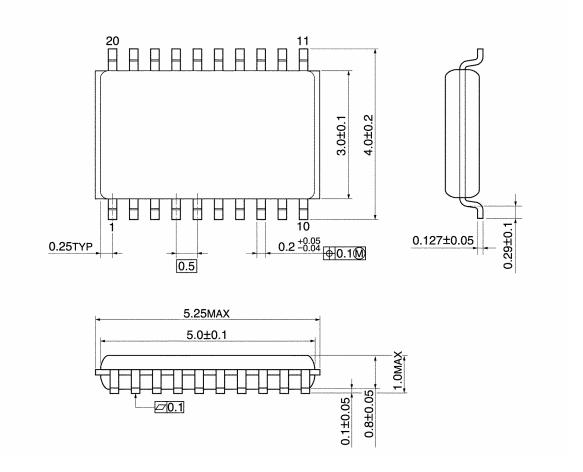


TSSOP20-P-0044-0.65A Unit: mm



Weight: 0.08 g (typ.)

VSSOP20-P-0030-0.50 Unit: mm



Weight: 0.03 g (typ.)

Note: Lead (Pb)-Free Packages

SOP20-P-300-1.27A TSSOP20-P-0044-0.65A VSSOP20-P-0030-0.50

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